Low-power buffer/line driver; 3-state Rev. 10.1 — 11 July 2023

1. General description

The 74AUP1G125 is a single buffer/line driver with 3-state output. Schmitt-trigger action at all inputs makes the circuit tolerant of slower input rise and fall times. This device ensures very low static and dynamic power consumption across the entire V_{CC} range from 0.8 V to 3.6 V.

This device is fully specified for partial power down applications using I_{OFF} . The I_{OFF} circuitry disables the output, preventing the potentially damaging backflow current through the device when it is powered down.

2. Features and benefits

- Wide supply voltage range from 0.8 V to 3.6 V
- High noise immunity
- Complies with JEDEC standards:
 - JESD8-12 (0.8 V to 1.3 V)
 - JESD8-11 (0.9 V to 1.65 V)
 - JESD8-7 (1.2 V to 1.95 V)
 - JESD8-5 (1.8 V to 2.7 V)
 - JESD8-B (2.7 V to 3.6 V)
- Low static power consumption; I_{CC} = 0.9 μA (maximum)
- Latch-up performance exceeds 100 mA per JESD 78 Class II
- Inputs accept voltages up to 3.6 V
- Low noise overshoot and undershoot < 10 % of V_{CC}
- Input-disable feature allows floating input conditions
- I_{OFF} circuitry provides partial Power-down mode operation
- Multiple package options
- ESD protection:
 - HBM: ANSI/ESDA/JEDEC JS-001 class 3A exceeds 5000 V
 - CDM: ANSI/ESDA/JEDEC JS-002 class C3 exceeds 1000 V
- Specified from -40 °C to +85 °C and -40 °C to +125 °C

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3. Ordering information

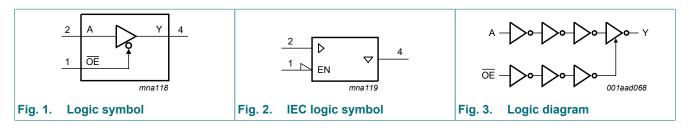
Type number	Package	Package								
	Temperature range	Name	Description	Version						
74AUP1G125GW	-40 °C to +125 °C	TSSOP5	plastic thin shrink small outline package; 5 leads; body width 1.25 mm	<u>SOT353-1</u>						
74AUP1G125GM	-40 °C to +125 °C	XSON6	plastic extremely thin small outline package; no leads; 6 terminals; body 1 × 1.45 × 0.5 mm	<u>SOT886</u>						
74AUP1G125GN	-40 °C to +125 °C	XSON6	extremely thin small outline package; no leads; 6 terminals; body 0.9 × 1.0 × 0.35 mm	<u>SOT1115</u>						
74AUP1G125GS	-40 °C to +125 °C	XSON6	extremely thin small outline package; no leads; 6 terminals; body 1.0 × 1.0 × 0.35 mm	<u>SOT1202</u>						
<u>74AUP1G125GX</u>	-40 °C to +125 °C	X2SON5	plastic thermal enhanced extremely thin small outline package; no leads; 5 terminals; body 0.8 × 0.8 × 0.32 mm	<u>SOT1226-3</u>						

4. Marking

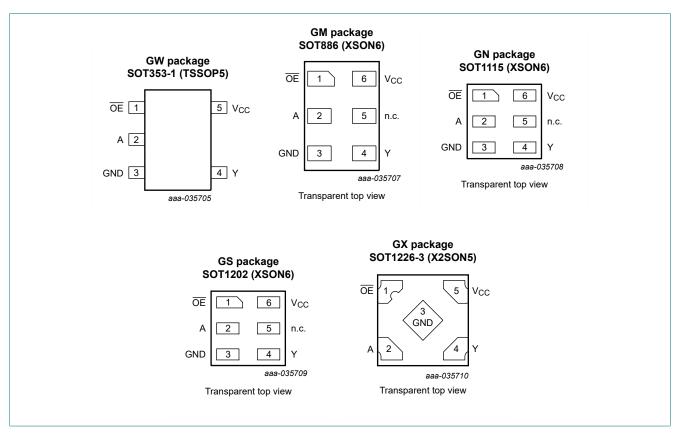
Table 2. Marking	
Type number	Marking code [1]
74AUP1G125GW	рМ
74AUP1G125GM	рМ
74AUP1G125GN	pM
74AUP1G125GS	рМ
74AUP1G125GX	рМ

[1] The pin 1 indicator is located on the lower left corner of the device, below the marking code.

5. Functional diagram



6. Pinning information



6.1. Pinning

6.2. Pin description

Table 3. Pin descrip	tion				
Symbol	Pin	Pin			
	TSSOP5 and X2SON5	XSON6			
OE	1	1	output enable input		
A	2	2	data input		
GND	3	3	ground (0 V)		
Y	4	4	data output		
n.c.	-	5	not connected		
V _{CC}	5	6	supply voltage		

7. Functional description

Table 4. Function table

H = HIGH voltage level; L = LOW voltage level; X = Don't care; Z = high-impedance OFF-state.

Input OE	Output	
OE	Α	Y
L	L	L
L	Н	Н
Н	X	Z

8. Limiting values

Table 5. Limiting values

In accordance with the Absolute Maximum Rating System (IEC 60134). Voltages are referenced to GND (ground = 0 V).

			-			
Symbol	Parameter	Conditions		Min	Мах	Unit
V _{CC}	supply voltage			-0.5	+4.6	V
I _{IK}	input clamping current	V ₁ < 0 V		-50	-	mA
VI	input voltage		[1]	-0.5	+4.6	V
I _{OK}	output clamping current	V _O < 0 V		-50	-	mA
Vo	output voltage	Active mode	[1]	-0.5	V _{CC} + 0.5	V
		Power-down mode; V_{CC} = 0 V	[1]	-0.5	+4.6	V
lo	output current	$V_{O} = 0 V \text{ to } V_{CC}$		-	±20	mA
I _{CC}	supply current			-	+50	mA
I _{GND}	ground current			-50	-	mA
T _{stg}	storage temperature			-65	+150	°C
P _{tot}	total power dissipation	T _{amb} = -40 °C to +125 °C	[2]	-	250	mW

[1] The input and output voltage ratings may be exceeded if the input and output current ratings are observed.

[2] For SOT353-1 (TSSOP5) package: P_{tot} derates linearly with 3.3 mW/K above 74 °C.

For SOT886 (XSON6) package: P_{tot} derates linearly with 3.3 mW/K above 74 °C.

For SOT1115 (XSON6) package: P_{tot} derates linearly with 3.2 mW/K above 71 °C.

For SOT1202 (XSON6) package: Ptot derates linearly with 3.3 mW/K above 74 °C.

For SOT1226-3 (X2SON5) package: P_{tot} derates linearly with 3.0 mW/K above 67 °C.

9. Recommended operating conditions

Table 6.	Recommended operating conditior	IS			
Symbol	Parameter	Min	Мах	Unit	
V _{CC}	supply voltage		0.8	3.6	V
VI	input voltage		0	3.6	V
Vo	output voltage	Active mode	0	V _{CC}	V
		Power-down mode; V _{CC} = 0 V	0	3.6	V
T _{amb}	ambient temperature		-40	+125	°C
Δt/ΔV	input transition rise and fall rate	V _{CC} = 0.8 V to 3.6 V	0	200	ns/V

10. Static characteristics

Table 7. Static characteristics

At recommended operating conditions; voltages are referenced to GND (ground = 0 V).

Symbol	Parameter	Conditions	Min	Тур	Мах	Unit
T _{amb} = 2	25 °C					
V _{IH}	HIGH-level input	V _{CC} = 0.8 V	0.70 × V _{CC}	-	-	V
	voltage	V _{CC} = 0.9 V to 1.95 V	0.65 × V _{CC}	-	-	V
		V _{CC} = 2.3 V to 2.7 V	1.6	-	-	V
		V _{CC} = 3.0 V to 3.6 V	2.0	-	-	V
V _{IL}	LOW-level input	V _{CC} = 0.8 V	-	-	0.30 × V _{CC}	V
	voltage	V _{CC} = 0.9 V to 1.95 V	-	-	0.35 × V _{CC}	V
		V _{CC} = 2.3 V to 2.7 V	-	-	0.7	V
		V _{CC} = 3.0 V to 3.6 V	-	-	0.9	V
V _{OH} HIGH-level output		$V_{I} = V_{IH}$ or V_{IL}				
	voltage	I_{O} = -20 µA; V_{CC} = 0.8 V to 3.6 V	V _{CC} - 0.1	-	-	V
		I _O = -1.1 mA; V _{CC} = 1.1 V	0.75 × V _{CC}	-	-	V
		I _O = -1.7 mA; V _{CC} = 1.4 V	1.11	-	-	V
		I _O = -1.9 mA; V _{CC} = 1.65 V	1.32	-	-	V
		I _O = -2.3 mA; V _{CC} = 2.3 V	2.05	-	-	V
		$I_0 = -3.1 \text{ mA}; V_{CC} = 2.3 \text{ V}$	1.9	-	-	V
		$I_0 = -2.7 \text{ mA}; V_{CC} = 3.0 \text{ V}$	2.72	-	-	V
		$I_{O} = -4.0 \text{ mA}; V_{CC} = 3.0 \text{ V}$	2.6	-	-	V
V _{OL}	LOW-level output	$V_{I} = V_{IH} \text{ or } V_{IL}$				
	voltage	$I_0 = 20 \ \mu A; V_{CC} = 0.8 \ V \text{ to } 3.6 \ V$	-	-	0.1	V
		$I_0 = 1.1 \text{ mA; } V_{CC} = 1.1 \text{ V}$	-	-	0.3 × V _{CC}	V
		I _O = 1.7 mA; V _{CC} = 1.4 V	-	-	0.31	V
		$I_0 = 1.9 \text{ mA; } V_{CC} = 1.65 \text{ V}$	-	-	0.31	V
		$I_0 = 2.3 \text{ mA; } V_{CC} = 2.3 \text{ V}$	-	-	0.31	V
		$I_0 = 3.1 \text{ mA}; V_{CC} = 2.3 \text{ V}$	-	-	0.44	V
		$I_0 = 2.7 \text{ mA}; V_{CC} = 3.0 \text{ V}$	-	-	0.31	V
		$I_0 = 4.0 \text{ mA}; V_{CC} = 3.0 \text{ V}$	-	-	0.44	V
I	input leakage current	$V_{I} = GND \text{ to } 3.6 \text{ V}; V_{CC} = 0 \text{ V to } 3.6 \text{ V}$	-	-	±0.1	μA
I _{OZ}	OFF-state output current	$V_{I} = V_{IH} \text{ or } V_{IL}; V_{O} = 0 \text{ V to } 3.6 \text{ V};$ $V_{CC} = 0 \text{ V to } 3.6 \text{ V}$	-	-	±0.1	μA
I _{OFF}	power-off leakage current	$V_{\rm I} \text{ or } V_{\rm O} = 0 \text{ V to } 3.6 \text{ V; } V_{\rm CC} = 0 \text{ V}$	-	-	±0.2	μA
ΔI _{OFF}	additional power-off leakage current	V_{1} or V_{0} = 0 V to 3.6 V; V_{CC} = 0 V to 0.2 V	-	-	±0.2	μA
I _{CC}	supply current	$V_{I} = GND \text{ or } V_{CC}; I_{O} = 0 \text{ A};$ $V_{CC} = 0.8 \text{ V to } 3.6 \text{ V}$	-	-	0.5	μA
ΔI _{CC}	additional supply current	data input; V _I = V _{CC} - 0.6 V; I _O = 0 A; V _{CC} = 3.3 V	[1] -	-	40	μA
		$\overline{\text{OE}}$ input; V _I = V _{CC} - 0.6 V; I _O = 0 A; V _{CC} = 3.3 V	[1] -	-	110	μA
		all inputs; V _I = GND to 3.6 V; \overline{OE} = V _{CC} ; V _{CC} = 0.8 V to 3.6 V	[2] -	-	1	μA

Low-power buffer/line driver; 3-state

Symbol	Parameter	Conditions	Min	Тур	Мах	Unit
CI	input capacitance	V_{CC} = 0 V to 3.6 V; V _I = GND or V _{CC}	-	0.9	-	pF
Co	output capacitance	output enabled; $V_0 = GND$; $V_{CC} = 0 V$	-	1.7	-	pF
		output disabled; V _{CC} = 0 V to 3.6 V; V _O = GND or V _{CC}	-	1.5	-	pF
T _{amb} = -4	40 °C to +85 °C					
V _{IH}	HIGH-level input	V _{CC} = 0.8 V	0.70 × V _{CC}	-	-	V
	voltage	V _{CC} = 0.9 V to 1.95 V	0.65 × V _{CC}	-	-	V
		V _{CC} = 2.3 V to 2.7 V	1.6	-	-	V
		V _{CC} = 3.0 V to 3.6 V	2.0	-	-	V
V _{IL}	LOW-level input	V _{CC} = 0.8 V	-	-	0.30 × V _{CC}	V
	voltage	V _{CC} = 0.9 V to 1.95 V	-	-	0.35 × V _{CC}	V
		V _{CC} = 2.3 V to 2.7 V	-	-	0.7	V
		V _{CC} = 3.0 V to 3.6 V	-	-	0.9	V
V _{OH}	HIGH-level output	$V_{I} = V_{IH} \text{ or } V_{IL}$				
	voltage	I_{O} = -20 µA; V_{CC} = 0.8 V to 3.6 V	V _{CC} - 0.1	-	-	V
		I _O = -1.1 mA; V _{CC} = 1.1 V	0.7 × V _{CC}	-	-	V
		I _O = -1.7 mA; V _{CC} = 1.4 V	1.03	-	-	V
		I _O = -1.9 mA; V _{CC} = 1.65 V	1.30	-	-	V
		I _O = -2.3 mA; V _{CC} = 2.3 V	1.97	-	-	V
		I _O = -3.1 mA; V _{CC} = 2.3 V	1.85	-	-	V
		I _O = -2.7 mA; V _{CC} = 3.0 V	2.67	-	-	V
		I _O = -4.0 mA; V _{CC} = 3.0 V	2.55	-	-	V
V _{OL}	LOW-level output	$V_{I} = V_{IH} \text{ or } V_{IL}$				
	voltage	I_{O} = 20 µA; V_{CC} = 0.8 V to 3.6 V	-	-	0.1	V
		I _O = 1.1 mA; V _{CC} = 1.1 V	-	-	0.3 × V _{CC}	V
		I _O = 1.7 mA; V _{CC} = 1.4 V	-	-	0.37	V
		I _O = 1.9 mA; V _{CC} = 1.65 V	-	-	0.35	V
		I _O = 2.3 mA; V _{CC} = 2.3 V	-	-	0.33	V
		I _O = 3.1 mA; V _{CC} = 2.3 V	-	-	0.45	V
		I _O = 2.7 mA; V _{CC} = 3.0 V	-	-	0.33	V
		I _O = 4.0 mA; V _{CC} = 3.0 V	-	-	0.45	V
I _I	input leakage current	V_I = GND to 3.6 V; V_{CC} = 0 V to 3.6 V	-	-	±0.5	μA
I _{OZ}	OFF-state output current	$V_{I} = V_{IH} \text{ or } V_{IL}; V_{O} = 0 \text{ V to } 3.6 \text{ V};$ $V_{CC} = 0 \text{ V to } 3.6 \text{ V}$	-	-	±0.5	μA
I _{OFF}	power-off leakage current	V_1 or V_0 = 0 V to 3.6 V; V_{CC} = 0 V	-	-	±0.5	μA
ΔI _{OFF}	additional power-off leakage current	V_1 or V_0 = 0 V to 3.6 V; V_{CC} = 0 V to 0.2 V	-	-	±0.6	μA
I _{CC}	supply current	$V_{I} = GND \text{ or } V_{CC}; I_{O} = 0 \text{ A};$ $V_{CC} = 0.8 \text{ V to } 3.6 \text{ V}$	-	-	0.9	μA
ΔI _{CC}	additional supply current	data input; V _I = V _{CC} - 0.6 V; I _O = 0 A; V _{CC} = 3.3 V	[1] -	-	50	μA
		$\label{eq:optimal_constraint} \overline{\text{OE}} \text{ input; } V_{\text{I}} = V_{\text{CC}} - 0.6 \text{ V; } I_{\text{O}} = 0 \text{ A;} \\ V_{\text{CC}} = 3.3 \text{ V}$	[1] -	-	120	μA
		all inputs; V _I = GND to 3.6 V; \overline{OE} = V _{CC} ; V _{CC} = 0.8 V to 3.6 V	[2] -	-	1	μA

Low-power buffer/line driver; 3-state

Symbol	Parameter	Conditions		Min	Тур	Мах	Unit
T _{amb} = -	40 °C to +125 °C						
V _{IH}	HIGH-level input	V _{CC} = 0.8 V		0.75 × V _{CC}	-	-	V
	voltage	V _{CC} = 0.9 V to 1.95 V		0.70 × V _{CC}	-	-	V
		V _{CC} = 2.3 V to 2.7 V		1.6	-	-	V
		V _{CC} = 3.0 V to 3.6 V		2.0	-	-	V
V _{IL}	LOW-level input	V _{CC} = 0.8 V		-	-	0.25 × V _{CC}	V
	voltage	V _{CC} = 0.9 V to 1.95 V		-	-	0.30 × V _{CC}	V
		V _{CC} = 2.3 V to 2.7 V		-	-	0.7	V
		V _{CC} = 3.0 V to 3.6 V		-	-	0.9	V
V _{OH} HIGH-level output		$V_{I} = V_{IH} \text{ or } V_{IL}$					
	voltage	I_{O} = -20 µA; V_{CC} = 0.8 V to 3.6 V		V _{CC} - 0.11	-	-	V
		I _O = -1.1 mA; V _{CC} = 1.1 V		$0.6 \times V_{CC}$	-	-	V
		I _O = -1.7 mA; V _{CC} = 1.4 V		0.93	-	-	V
		I _O = -1.9 mA; V _{CC} = 1.65 V		1.17	-	-	V
		I _O = -2.3 mA; V _{CC} = 2.3 V		1.77	-	-	V
		I _O = -3.1 mA; V _{CC} = 2.3 V		1.67	-	-	V
		I _O = -2.7 mA; V _{CC} = 3.0 V		2.40	-	-	V
		I _O = -4.0 mA; V _{CC} = 3.0 V		2.30	-	-	V
-	LOW-level output	$V_{I} = V_{IH} \text{ or } V_{IL}$					
	voltage	I_{O} = 20 µA; V_{CC} = 0.8 V to 3.6 V		-	-	0.11	V
		I _O = 1.1 mA; V _{CC} = 1.1 V		-	-	$0.33 \times V_{CC}$	V
		I _O = 1.7 mA; V _{CC} = 1.4 V		-	-	0.41	V
		I _O = 1.9 mA; V _{CC} = 1.65 V		-	-	0.39	V
		I _O = 2.3 mA; V _{CC} = 2.3 V		-	-	0.36	V
		I _O = 3.1 mA; V _{CC} = 2.3 V		-	-	0.50	V
		I _O = 2.7 mA; V _{CC} = 3.0 V		-	-	0.36	V
		I _O = 4.0 mA; V _{CC} = 3.0 V		-	-	0.50	V
lı	input leakage current	V_{I} = GND to 3.6 V; V_{CC} = 0 V to 3.6 V		-	-	±0.75	μA
I _{OZ}	OFF-state output current	$V_{I} = V_{IH} \text{ or } V_{IL}; V_{O} = 0 \text{ V to } 3.6 \text{ V};$ $V_{CC} = 0 \text{ V to } 3.6 \text{ V}$		-	-	±0.75	μA
I _{OFF}	power-off leakage current	V_{I} or V_{O} = 0 V to 3.6 V; V_{CC} = 0 V		-	-	±0.75	μA
Δl _{OFF}	additional power-off leakage current	V_{I} or V_{O} = 0 V to 3.6 V; V_{CC} = 0 V to 0.2 V		-	-	±0.75	μA
I _{CC}	supply current	$V_{I} = GND \text{ or } V_{CC}; I_{O} = 0 \text{ A};$ $V_{CC} = 0.8 \text{ V to } 3.6 \text{ V}$		-	-	1.4	μA
ΔI _{CC}	additional supply current	data input; $V_1 = V_{CC} - 0.6 \text{ V}$; $I_0 = 0 \text{ A}$; $V_{CC} = 3.3 \text{ V}$	[1]	-	-	75	μA
		$\overline{\text{OE}}$ input; V _I = V _{CC} - 0.6 V; I _O = 0 A; V _{CC} = 3.3 V	[1]	-	-	180	μA
		all inputs; V _I = GND to 3.6 V; \overline{OE} = V _{CC} ; V _{CC} = 0.8 V to 3.6 V	[2]	-	-	1	μA

[1] [2]

One input at V_{CC} - 0.6 V, other input at V_{CC} or GND. To show I_{CC} remains very low when the input-disable feature is enabled.

11. Dynamic characteristics

Table 8. Dynamic characteristics

Voltages are referenced to GND (ground = 0 V); for test circuit see Fig. 6.

Symbol	Parameter	Conditions	Т	_{amb} = 25 °	°C	T _{an} -40 °C t	T _{amb} = -40 °C to +85 °C		T _{amb} = -40 °C to +125 °C	
			Min	Typ [1]	Max	Min	Мах	Min	Max	-
C _L = 5 p	F									
t _{pd}		A to Y; see <u>Fig. 4</u> [2]								
	delay	V _{CC} = 0.8 V	-	20.6	-	-	-	-	-	ns
		V _{CC} = 1.1 V to 1.3 V	2.8	5.5	10.5	2.5	11.7	2.5	12.9	ns
		V _{CC} = 1.4 V to 1.6 V	2.2	3.9	6.1	2.0	7.3	2.0	8.1	ns
		V _{CC} = 1.65 V to 1.95 V	1.9	3.2	4.8	1.7	6.1	1.7	6.7	ns
		V _{CC} = 2.3 V to 2.7 V	1.6	2.6	3.6	1.4	4.3	1.4	4.9	ns
		V _{CC} = 3.0 V to 3.6 V	1.4	2.4	3.1	1.2	3.9	1.2	4.4	ns
t _{en} enable time	OE to Y; see Fig. 5 [3]									
		V _{CC} = 0.8 V	-	69.9	-	-	-	-	-	ns
		V _{CC} = 1.1 V to 1.3 V	3.1	6.1	11.8	2.9	13.9	2.9	15.4	ns
		V _{CC} = 1.4 V to 1.6 V	2.5	4.2	6.6	2.3	7.7	2.3	8.3	ns
		V _{CC} = 1.65 V to 1.95 V	2.1	3.4	5.1	2.0	6.2	2.0	6.8	ns
		V _{CC} = 2.3 V to 2.7 V	1.8	2.6	3.7	1.7	4.5	1.7	5.0	ns
		V _{CC} = 3.0 V to 3.6 V	1.7	2.4	3.1	1.7	3.5	1.7	3.9	ns
t _{dis}	disable time	OE to Y; see <u>Fig. 5</u> [4]								
		V _{CC} = 0.8 V	-	14.3	-	-	-	-	-	ns
		V _{CC} = 1.1 V to 1.3 V	2.7	4.3	6.5	2.7	7.3	2.7	8.2	ns
		V _{CC} = 1.4 V to 1.6 V	2.1	3.2	4.4	2.1	5.1	2.1	5.7	ns
		V _{CC} = 1.65 V to 1.95 V	2.0	3.0	4.3	2.0	5.0	2.0	5.7	ns
		V _{CC} = 2.3 V to 2.7 V	1.4	2.2	2.9	1.4	3.3	1.4	4.1	ns
		V _{CC} = 3.0 V to 3.6 V	1.7	2.5	3.2	1.7	3.4	1.7	3.9	ns
C _L = 10	pF					1	1	I		
t _{pd}	propagation	A to Y; see Fig. 4 [2]								
	delay	V _{CC} = 0.8 V	-	24.0	-	-	-	-	-	ns
		V _{CC} = 1.1 V to 1.3 V	3.2	6.4	12.3	3.0	13.8	3.0	15.2	ns
		V _{CC} = 1.4 V to 1.6 V	2.1	4.5	7.3	1.9	8.5	1.9	9.4	ns
		V _{CC} = 1.65 V to 1.95 V	1.9	3.8	5.5	1.7	6.8	1.7	7.6	ns
		V _{CC} = 2.3 V to 2.7 V	2.1	3.2	4.2	1.6	5.3	1.6	5.9	ns
		V _{CC} = 3.0 V to 3.6 V	1.8	3.0	3.8	1.6	4.6	1.6	5.2	ns
t _{en}	enable time	OE to Y; see Fig. 5 [3]								-
		V _{CC} = 0.8 V	-	73.7	-	-	-	-	-	ns
		V _{CC} = 1.1 V to 1.3 V	3.6	6.9	13.5	3.4	15.8	3.4	17.5	ns
		V _{CC} = 1.4 V to 1.6 V	2.3	4.8	7.7	2.2	8.6	2.2	9.4	ns
		V _{CC} = 1.65 V to 1.95 V	2.0	3.9	5.8	1.9	6.8	1.9	7.4	ns
		V _{CC} = 2.3 V to 2.7 V	1.8	3.2	4.3	1.7	5.3	1.7	5.9	ns
		V _{CC} = 3.0 V to 3.6 V	1.7	3.0	3.9	1.7	4.3	1.7	4.8	ns

Low-power buffer/line driver; 3-state

Symbol	Parameter	Conditions	T _{amb} = 25 °C			T _{amb} = -40 °C to +85 °C		T _{amb} = -40 °C to +125 °C		Unit
			Min	Typ [1]	Max	Min	Мах	Min	Мах	
t _{dis}	disable time	OE to Y; see <u>Fig. 5</u> [4]								
		V _{CC} = 0.8 V	-	32.7	-	-	-	-	-	ns
		V _{CC} = 1.1 V to 1.3 V	3.4	5.4	7.9	3.4	8.8	3.4	9.9	ns
		V _{CC} = 1.4 V to 1.6 V	2.2	4.1	5.5	2.2	6.2	2.2	7.1	ns
		V _{CC} = 1.65 V to 1.95 V	2.2	4.2	5.6	1.9	6.3	1.9	7.1	ns
		V _{CC} = 2.3 V to 2.7 V	1.7	3.0	3.8	1.7	4.5	1.7	5.1	ns
		V _{CC} = 3.0 V to 3.6 V	2.1	3.8	4.8	1.7	5.0	1.7	5.6	ns
C _L = 15	pF						•		-	
t _{pd}		A to Y; see Fig. 4 [2]								
	delay	V _{CC} = 0.8 V	-	27.4	-	-	-	-	-	ns
		V _{CC} = 1.1 V to 1.3 V	3.6	7.2	14.1	3.3	15.8	3.3	17.5	ns
	-	V _{CC} = 1.4 V to 1.6 V	3.0	5.1	8.1	2.5	9.8	2.5	10.9	ns
		V _{CC} = 1.65 V to 1.95 V	2.2	4.3	6.3	2.0	7.9	2.0	8.8	ns
		V _{CC} = 2.3 V to 2.7 V	2.0	3.7	4.9	1.8	6.0	1.8	6.7	ns
		V _{CC} = 3.0 V to 3.6 V	2.0	3.5	4.4	1.8	5.4	1.8	6.1	ns
t _{en}	enable time	OE to Y; see Fig. 5 [3]								
		V _{CC} = 0.8 V	-	77.5	-	-	-	-	-	ns
		V _{CC} = 1.1 V to 1.3 V	4.0	7.7	15.2	3.7	17.6	3.7	19.6	ns
		V _{CC} = 1.4 V to 1.6 V	3.0	5.3	8.4	2.5	9.8	2.5	10.7	ns
		V _{CC} = 1.65 V to 1.95 V	2.3	4.4	6.5	2.1	7.7	2.1	8.5	ns
		V _{CC} = 2.3 V to 2.7 V	2.1	3.6	5.0	2.0	6.1	2.0	6.8	ns
		V _{CC} = 3.0 V to 3.6 V	2.0	3.5	4.5	1.9	4.9	1.9	5.5	ns
t _{dis}	disable time	OE to Y; see <u>Fig. 5</u> [4]								
		V _{CC} = 0.8 V	-	60.8	-	-	-	-	-	ns
		V _{CC} = 1.1 V to 1.3 V	4.3	6.5	9.2	3.7	10.3	3.7	11.6	ns
		V _{CC} = 1.4 V to 1.6 V	3.0	5.0	6.5	2.5	7.4	2.5	8.4	ns
		V _{CC} = 1.65 V to 1.95 V	3.0	5.3	6.6	2.1	7.4	2.1	8.9	ns
		V _{CC} = 2.3 V to 2.7 V	2.1	3.8	4.9	2.0	5.1	2.0	6.4	ns
		V _{CC} = 3.0 V to 3.6 V	2.9	5.0	6.2	1.9	6.6	1.9	7.4	ns
C _L = 30	pF					1		1		1
t _{pd}		A to Y; see Fig. 4 [2]								
	delay	V _{CC} = 0.8 V	-	37.4	-	-	-	-	-	ns
		V _{CC} = 1.1 V to 1.3 V	4.8	9.5	19.0	4.4	21.6	4.4	24.0	ns
		V _{CC} = 1.4 V to 1.6 V	4.0	6.7	10.8	3.0	13.0	3.0	14.5	ns
		V _{CC} = 1.65 V to 1.95 V	2.9	5.6	8.4	2.6	10.3	2.6	11.5	ns
		V _{CC} = 2.3 V to 2.7 V	2.7	4.8	6.3	2.5	7.8	2.5	8.7	ns
		V _{CC} = 3.0 V to 3.6 V	2.7	4.6	5.8	2.5	7.5	2.5	8.3	ns

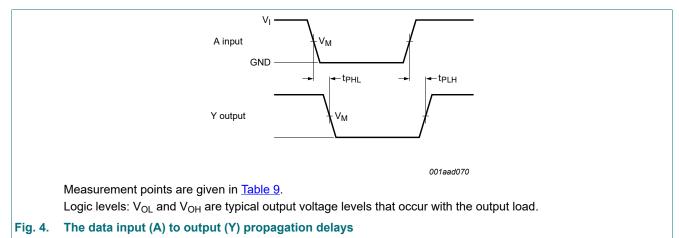
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Low-power buffer/line driver; 3-state

Symbol	Parameter	Conditions	T _{amb} = 25 °C			T _{amb} = -40 °C to +85 °C		T _{amb} = -40 °C to +125 °C		Unit
			Min	Typ [1]	Max	Min	Max	Min	Max	
t _{en}	enable time	OE to Y; see <u>Fig. 5</u> [3]								
		V _{CC} = 0.8 V	-	88.9	-	-	-	-	-	ns
		V _{CC} = 1.1 V to 1.3 V	5.2	9.9	19.8	4.8	22.8	4.8	25.3	ns
		V _{CC} = 1.4 V to 1.6 V	4.0	6.8	10.8	3.1	12.6	3.1	14.1	ns
		V _{CC} = 1.65 V to 1.95 V	3.0	5.6	8.5	2.8	10.2	2.8	11.3	ns
		V _{CC} = 2.3 V to 2.7 V	2.7	4.8	6.5	2.6	7.8	2.6	8.8	ns
		V _{CC} = 3.0 V to 3.6 V	2.7	4.6	6.0	2.6	6.9	2.6	7.7	ns
t _{dis}	disable time	OE to Y; see <u>Fig. 5</u> [4]								
		V _{CC} = 0.8 V	-	49.9	-	-	-	-	-	ns
		V _{CC} = 1.1 V to 1.3 V	6.0	9.9	13.3	4.8	14.8	4.8	16.5	ns
		V _{CC} = 1.4 V to 1.6 V	4.4	7.7	9.6	3.1	10.7	3.1	12.1	ns
		V _{CC} = 1.65 V to 1.95 V	5.1	8.7	11.1	2.8	12.4	2.8	13.8	ns
		V _{CC} = 2.3 V to 2.7 V	3.6	6.2	7.4	2.6	8.6	2.6	9.6	ns
		V _{CC} = 3.0 V to 3.6 V	5.2	8.7	10.5	2.6	10.8	2.6	13.1	ns
T _{amb} = 2	5 °C								1	
C _{PD}	power dissipation capacitance	f = 1 MHz; [5]								
		V _{CC} = 0.8 V	-	2.7	-	-	-	-	-	pF
		V _{CC} = 1.1 V to 1.3 V	-	2.8	-	-	-	-	-	pF
		V _{CC} = 1.4 V to 1.6 V	-	2.9	-	-	-	-	-	pF
		V _{CC} = 1.65 V to 1.95 V	-	3.0	-	-	-	-	-	pF
		V _{CC} = 2.3 V to 2.7 V	-	3.6	-	-	-	-	-	pF
		V _{CC} = 3.0 V to 3.6 V	-	4.2	-	-	-	-	-	pF

- All typical values are measured at nominal V_{CC} . [1]

- [1] All typical values are measured at nominal V_{CC}. [2] t_{pd} is the same as t_{PLH} and t_{PHL} . [3] t_{en} is the same as t_{PZH} and t_{PZL} . [4] t_{dis} is the same as t_{PHZ} and t_{PLZ} . [5] C_{PD} is used to determine the dynamic power dissipation (P_D in µW). $P_D = C_{PD} \times V_{CC}^2 \times f_i \times N + \Sigma(C_L \times V_{CC}^2 \times f_o)$ where: f_i = input frequency in MHz; $f_o = output$ frequency in MHz; C_{L} = output load capacitance in pF;
 - V_{CC} = supply voltage in V; N = number of inputs switching;
 - $\Sigma(C_L \times V_{CC}^2 \times f_o) = \text{sum of the outputs.}$



11.1. Waveforms and test circuit

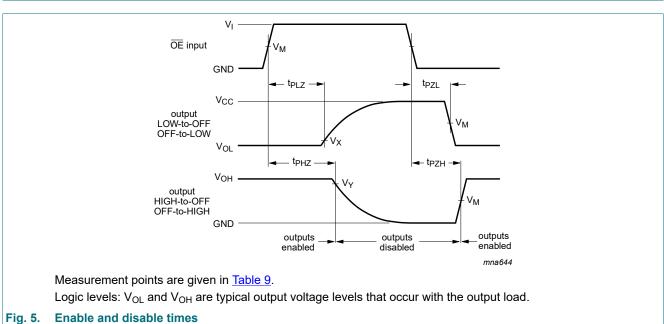


Table 9. Measurement points

Supply voltage	Input			Output		
V _{cc}	V _M	VI	t _r = t _f	V _M	V _X	V _Y
0.8 V to 1.6 V	$0.5 \times V_{CC}$	V _{CC}	≤ 3.0 ns	0.5 × V _{CC}	V _{OL} + 0.1 V	V _{OH} - 0.1 V
1.65 V to 2.7 V	$0.5 \times V_{CC}$	V _{CC}	≤ 3.0 ns	0.5 × V _{CC}	V _{OL} + 0.15 V	V _{OH} - 0.15 V
3.0 V to 3.6 V	$0.5 \times V_{CC}$	V _{CC}	≤ 3.0 ns	0.5 × V _{CC}	V _{OL} + 0.3 V	V _{OH} - 0.3 V

Low-power buffer/line driver; 3-state

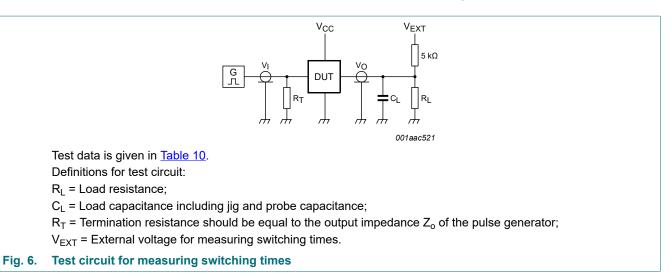


Table 10. Test data

Supply voltage	Load	V _{EXT}			
V _{CC}	CL	R _L [1]	t _{PLH} , t _{PHL}	t _{PZH} , t _{PHZ}	t _{PZL} , t _{PLZ}
0.8 V to 3.6 V	5 pF, 10 pF, 15 pF and 30 pF	5 kΩ or 1 MΩ	open	GND	$2 \times V_{CC}$

[1] For measuring enable and disable times $R_L = 5 k\Omega$.

For measuring propagation delays, setup and hold times and pulse width R_L = 1 M Ω .

12. Package outline

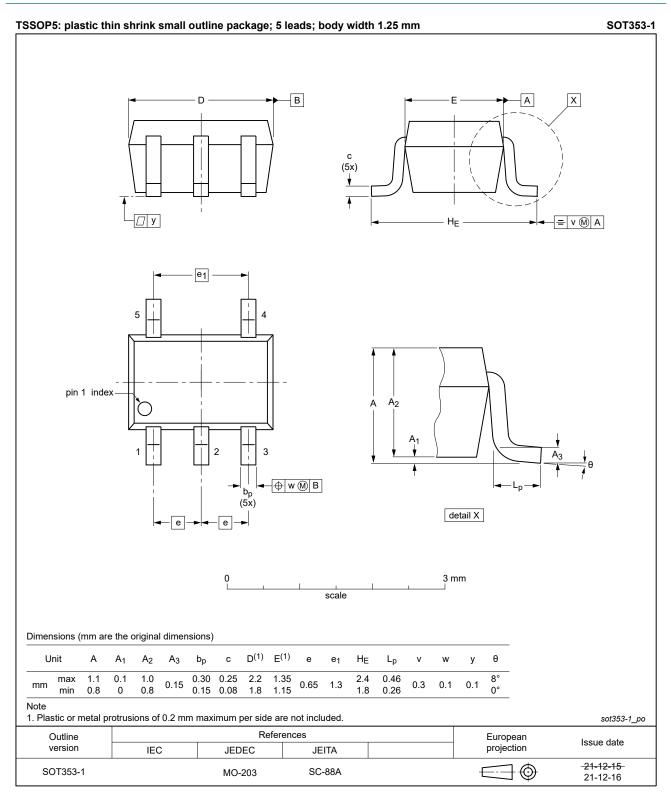


Fig. 7. Package outline SOT353-1 (TSSOP5)

Low-power buffer/line driver; 3-state

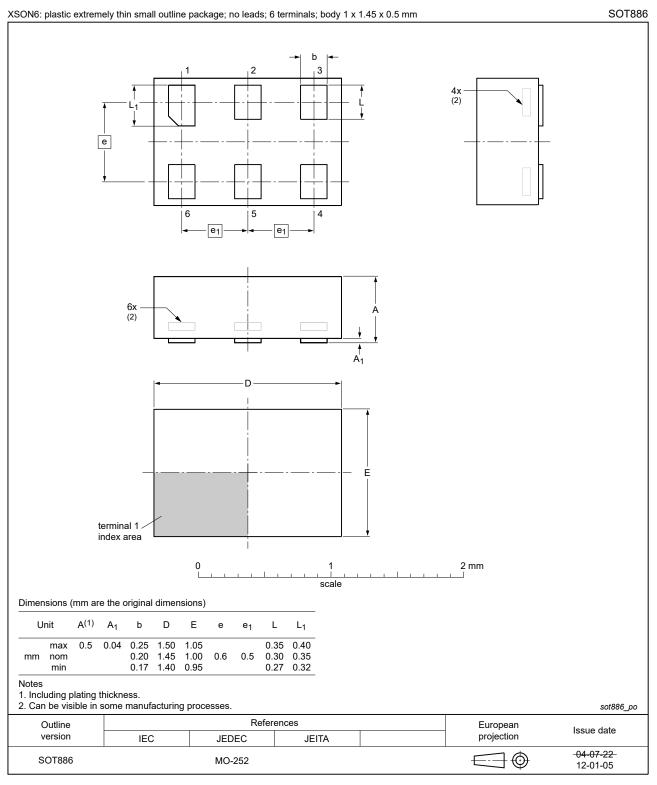
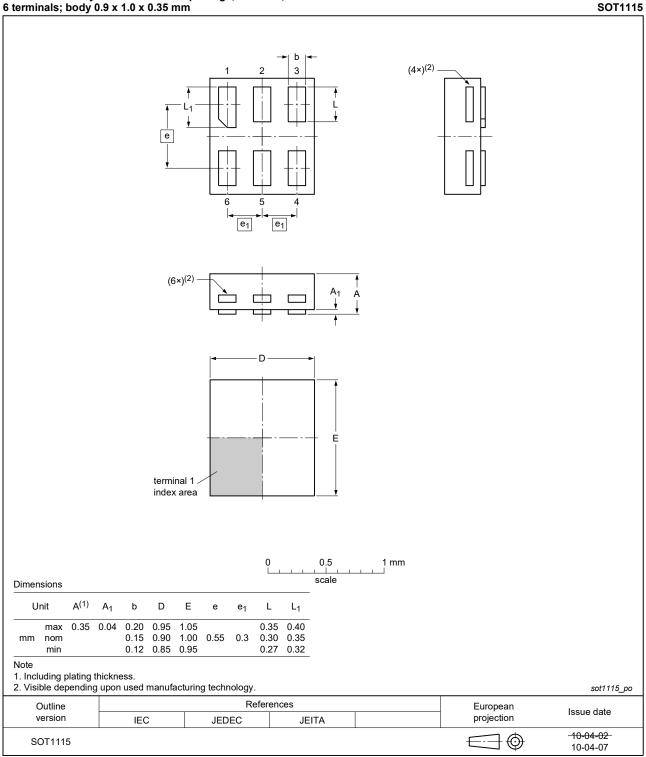


Fig. 8. Package outline SOT886 (XSON6)

Low-power buffer/line driver; 3-state

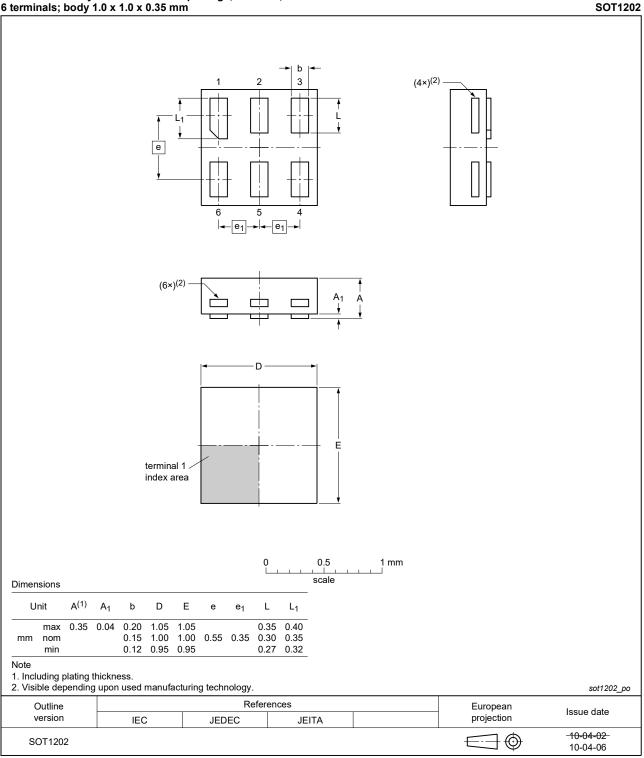
XSON6: extremely thin small outline package; no leads; 6 terminals; body 0.9 x 1.0 x 0.35 mm





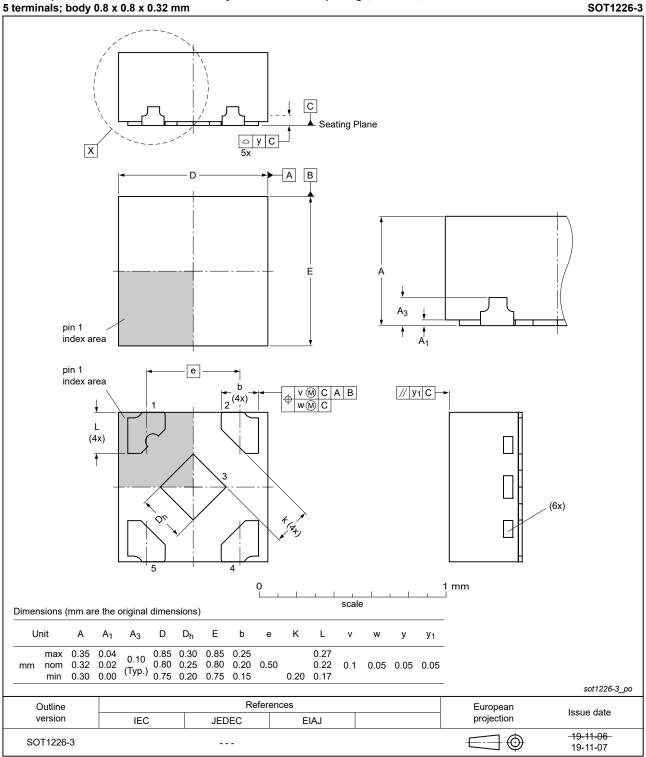
Low-power buffer/line driver; 3-state

XSON6: extremely thin small outline package; no leads; 6 terminals; body 1.0 x 1.0 x 0.35 mm





Low-power buffer/line driver; 3-state



X2SON5: plastic thermal enhanced extremely thin small outline package; no leads; 5 terminals; body 0.8 x 0.8 x 0.32 mm



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13. Abbreviations

Table 11. Abbreviations			
Acronym	Description		
CDM	Charged Device Model		
DUT	Device Under Test		
ESD	ElectroStatic Discharge		
НВМ	Human Body Model		

14. Revision history

Table 12. Revision history

Document ID	Release date	Data sheet status	Change notice	Supersedes			
74AUP1G125 v.10.1	20230711	Product data sheet	-	74AUP1G125 v.9			
Modifications:	Section 2: E	• <u>Section 2</u> : ESD specification updated according to the latest JEDEC standard.					
74AUP1G125 v.9	20220114	Product data sheet	-	74AUP1G125 v.8			
Modifications:	• <u>Fig. 7</u> : Pack	• Fig. 7: Package outline drawing for SOT353-1 (TSSOP5) has changed.					
74AUP1G125 v.8	20210421	Product data sheet	-	74AUP1G125 v.7			
Modifications:	 Type number Section 1 u 	Type number 74 Act 1012301 (0010317 A0010) removed.					
74AUP1G125 v.7	20180813	Product data sheet	-	74AUP1G125 v.6			
Modifications:	guidelines o	 The format of this data sheet has been redesigned to comply with the identity guidelines of Nexperia. Legal texts have been adapted to the new company name where appropriate. 					
74AUP1G125 v.6	20120815	Product data sheet	-	74AUP1G125 v.5			
Modifications:	Errata in ge	Errata in general description corrected					
74AUP1G125 v.5	20120731	Product data sheet	-	74AUP1G125 v.4			
Modifications:							
74AUP1G125 v.4	20111129	Product data sheet	-	74AUP1G125 v.3			
74AUP1G125 v.3	20100901	Product data sheet	-	74AUP1G125 v.2			
74AUP1G125 v.2	20060630	Product data sheet	-	74AUP1G125 v.1			
74AUP1G125 v.1	20050718	Product data sheet	-	-			

15. Legal information

Data sheet status

Document status [1][2]	Product status [3]	Definition
Objective [short] data sheet	Development	This document contains data from the objective specification for product development.
Preliminary [short] data sheet	Qualification	This document contains data from the preliminary specification.
Product [short] data sheet	Production	This document contains the product specification.

 Please consult the most recently issued document before initiating or completing a design.

- [2] The term 'short data sheet' is explained in section "Definitions".
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Product data sheet

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